NSN 5962-01-353-1631

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-353-1631

Body Length:	
1.280 inches	
Body Width:	
Between 0.220 inches and 0.310 inches	
Body Height:	
Between 0.140 inches and 0.185 inches	
Maximum Power Dissipation Rating:	
1.2 watts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Hermetically sealed and burn in and monolithic and positive outputs and electrostatic sensitive	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Complementary-metal oxide-semiconductor logic	
Input Circuit Pattern:	
22 input	
Case Outline Source And Designator:	
D-9 mil-m-38510	
Current Rating Per Characteristic:	
100.00 milliamperes reverse current, dc absolute	
Terminal Surface Treatment:	
Solder	
Product Name:	
And-or-logic array	
Voltage Rating And Type Per Characteristic:	
-0.5 volts power source and 7.0 volts power source	
Capitance Rating Per Characteristic:	
10.00 input pascal industrial light tank stock and 10.00 output pascal industrial light tank stock	
Time Rating Per Chacteristic:	
25.00 nanoseconds access	
Memory Device Type:	
Pal	
Test Data Document:	
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc	.)
Terminal Type And Quantity:	

24 printed circuit

NSN 5962-01-353-1631

Memory Microcircuit - Page 2 of 2



Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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